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Kind regards,

Team Nexperia

# 1 A very low V<sub>F</sub> MEGA Schottky barrier rectifiers Rev. 02 — 22 March 2007 Pro

**Product data sheet** 

### **Product profile**

#### 1.1 General description

Planar Maximum Efficiency General Application (MEGA) Schottky barrier rectifiers with an integrated guard ring for stress protection, encapsulated in small and flat lead Surface-Mounted Device (SMD) plastic packages.

Table 1. **Product overview** 

Type number	Package		Configuration
	NXP	JEITA	
PMEG3010CEH	SOD123F	-	single
PMEG3010CEJ	SOD323F	SC-90	single

#### 1.2 Features

Forward current: I<sub>F</sub> ≤ 1 A

Reverse voltage: V<sub>R</sub> ≤ 30 V

Very low forward voltage

Small and flat lead SMD plastic packages

#### 1.3 Applications

- Low voltage rectification
- High efficiency DC-to-DC conversion
- Switch mode power supply
- Reverse polarity protection
- Low power consumption applications

#### 1.4 Quick reference data

Table 2. **Quick reference data** 

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$I_{F}$	forward current	$T_{sp} \le 55  ^{\circ}C$	-	-	1	Α
$V_R$	reverse voltage		-	-	30	V
$V_{F}$	forward voltage	I <sub>F</sub> = 1 A	<u>[1]</u> _	450	520	mV

<sup>[1]</sup> Pulse test:  $t_p \le 300 \ \mu s$ ;  $\delta \le 0.02$ .



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## 2. Pinning information

Table 3. Pinning

Pin	Description	Simplified outline Symbol
1	cathode	[1]
2	anode	1 2 2 sym001
		001aab540

<sup>[1]</sup> The marking bar indicates the cathode.

## 3. Ordering information

Table 4. Ordering information

Type number	Package	ackage				
	Name	Description	Version			
PMEG3010CEH	-	plastic surface-mounted package; 2 leads	SOD123F			
PMEG3010CEJ	SC-90	plastic surface-mounted package; 2 leads	SOD323F			

### 4. Marking

Table 5. Marking codes

Type number	Marking code
PMEG3010CEH	C8
PMEG3010CEJ	EN

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### 5. Limiting values

Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{R}$	reverse voltage		-	30	V
I <sub>F</sub>	forward current	$T_{sp} \le 55  ^{\circ}C$	-	1	Α
I <sub>FRM</sub>	repetitive peak forward current	$\begin{array}{l} t_p \leq 1 \text{ ms;} \\ \delta \leq 0.25 \end{array}$	-	7	Α
I <sub>FSM</sub>	non-repetitive peak forward current	square wave; t <sub>p</sub> = 8 ms			
	PMEG3010CEH		-	9	Α
	PMEG3010CEJ		-	10	Α
P <sub>tot</sub>	total power dissipation	$T_{amb} \le 25  ^{\circ}C$			
	PMEG3010CEH		<u>[1]</u> _	375	mW
			[2] _	830	mW
	PMEG3010CEJ		<u>[1]</u> -	350	mW
			[2] _	830	mW
Tj	junction temperature		-	150	°C
T <sub>amb</sub>	ambient temperature		-65	+150	°C
T <sub>stg</sub>	storage temperature		-65	+150	°C

<sup>[1]</sup> Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

#### 6. Thermal characteristics

Table 7. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient	in free air	<u>[1]</u>			
	PMEG3010CEH		[2] _	-	330	K/W
			[3] _	-	150	K/W
	PMEG3010CEJ		[2] _	-	350	K/W
			[3] _	-	150	K/W
$R_{th(j-sp)}$	thermal resistance from junction to solder point		<u>[4]</u>			
	PMEG3010CEH		-	-	60	K/W
	PMEG3010CEJ		-	-	55	K/W

<sup>[1]</sup> For Schottky barrier diodes thermal runaway has to be considered, as in some applications the reverse power losses P<sub>R</sub> are a significant part of the total power losses.

<sup>[2]</sup> Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for cathode 1 cm<sup>2</sup>.

<sup>[2]</sup> Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

<sup>[3]</sup> Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for cathode 1 cm<sup>2</sup>.

<sup>[4]</sup> Soldering point of cathode tab.

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### 7. Characteristics

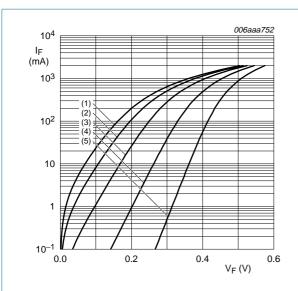
Table 8. Characteristics

 $T_{amb} = 25 \,^{\circ}C$  unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{F}$	forward voltage		<u>[1]</u>			
		$I_F = 1 \text{ mA}$	-	200	240	mV
		$I_F = 10 \text{ mA}$	-	260	310	mV
		I <sub>F</sub> = 100 mA	-	330	390	mV
		$I_F = 500 \text{ mA}$	-	400	440	mV
		I <sub>F</sub> = 700 mA	-	420	450	mV
		I <sub>F</sub> = 1 A	-	450	520	mV
I <sub>R</sub>	reverse current	$V_R = 5 V$	-	1.2	-	μΑ
		V <sub>R</sub> = 10 V	-	1.8	-	μΑ
		V <sub>R</sub> = 30 V	-	10	50	μΑ
C <sub>d</sub>	diode capacitance	$V_R = 1 V$ ; $f = 1 MHz$	-	90	100	pF

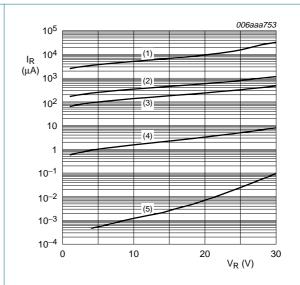
<sup>[1]</sup> Pulse test:  $t_p \le 300~\mu s;~\delta \le 0.02.$ 

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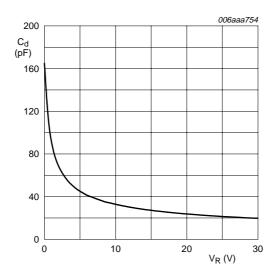
- (1)  $T_{amb} = 150 \, ^{\circ}C$
- (2)  $T_{amb} = 125 \, ^{\circ}C$
- (3)  $T_{amb} = 85 \, ^{\circ}C$
- (4)  $T_{amb} = 25 \, ^{\circ}C$
- (5)  $T_{amb} = -40 \, ^{\circ}C$

Fig 1. Forward current as a function of forward voltage; typical values



- (1)  $T_{amb} = 150 \, ^{\circ}C$
- (2)  $T_{amb} = 125 \, ^{\circ}C$
- (3)  $T_{amb} = 85 \, ^{\circ}C$
- (4)  $T_{amb} = 25 \, ^{\circ}C$
- (5)  $T_{amb} = -40 \, ^{\circ}C$

Fig 2. Reverse current as a function of reverse voltage; typical values

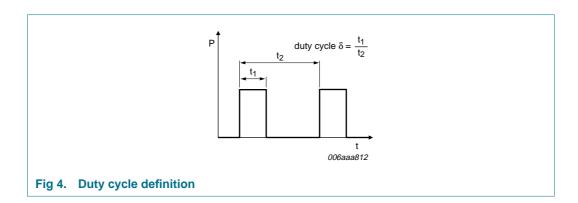


 $f = 1 \text{ MHz}; T_{amb} = 25 \,^{\circ}\text{C}$ 

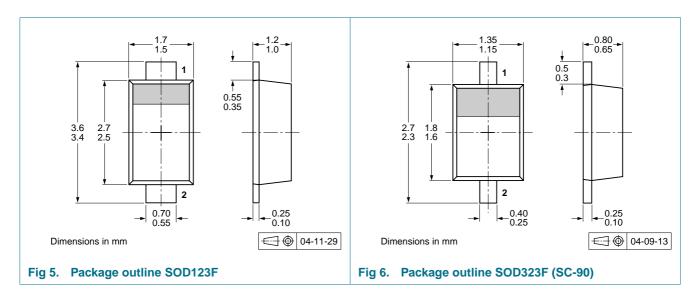
Fig 3. Diode capacitance as a function of reverse voltage; typical values

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### 8. Test information



## 9. Package outline



## 10. Packing information

Table 9. Packing methods

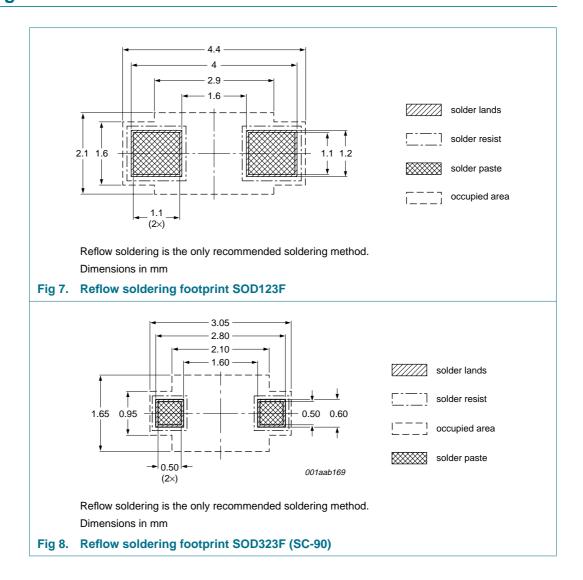
The indicated -xxx are the last three digits of the 12NC ordering code.[1]

Type number	Package	Description	Packing of	Packing quantity	
			3000	10000	
PMEG3010CEH	SOD123F	4 mm pitch, 8 mm tape and reel	-115	-135	
PMEG3010CEJ	SOD323F	_			

[1] For further information and the availability of packing methods, see Section 14.

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## 11. Soldering



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## 12. Revision history

#### Table 10. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes		
PMEG3010CEH_PMEG3010CEJ_2	20070322	Product data sheet	-	PMEG3010CEJ_1		
Modifications:		of this data sheet has beel delines of NXP Semicondu	•	oly with the new		
	<ul> <li>Legal texts</li> </ul>	have been adapted to the	new company name	where appropriate.		
	<ul> <li>Type number PMEG3010CEH added</li> </ul>					
	<ul><li>Section 1.1</li></ul>	"General description": am	ended			
	• Table 1 "Pr	oduct overview": added				
	• Table 7 "Th	ermal characteristics": Tab	le note 1 amended			
	<ul> <li>Table 8 "Ch</li> </ul>	naracteristics": V <sub>F</sub> forward v	oltage maximum valu	ues amended		
	<ul><li>Section 8 "</li></ul>	Test information": added				
PMEG3010CEJ_1	20060411	Product data sheet	-	-		

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### 13. Legal information

#### 13.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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## PMEG3010CEH; PMEG3010CEJ

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